

# **MOSFET Maximum Ratings** T<sub>J</sub> = 25°C unless otherwise noted.

Symbol	Parameter	Ratings	Units		
V <sub>DSS</sub>	Drain-to-Source Voltage		60	V	
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V	
I <sub>D</sub>	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> = 25°C	25	Α	
	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4		
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	14.5	mJ	
P <sub>D</sub>	Power Dissipation		48.4	W	
	Derate Above 25°C		0.32	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		3.1	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient (Note 3)		52	°C/W	

Notes:

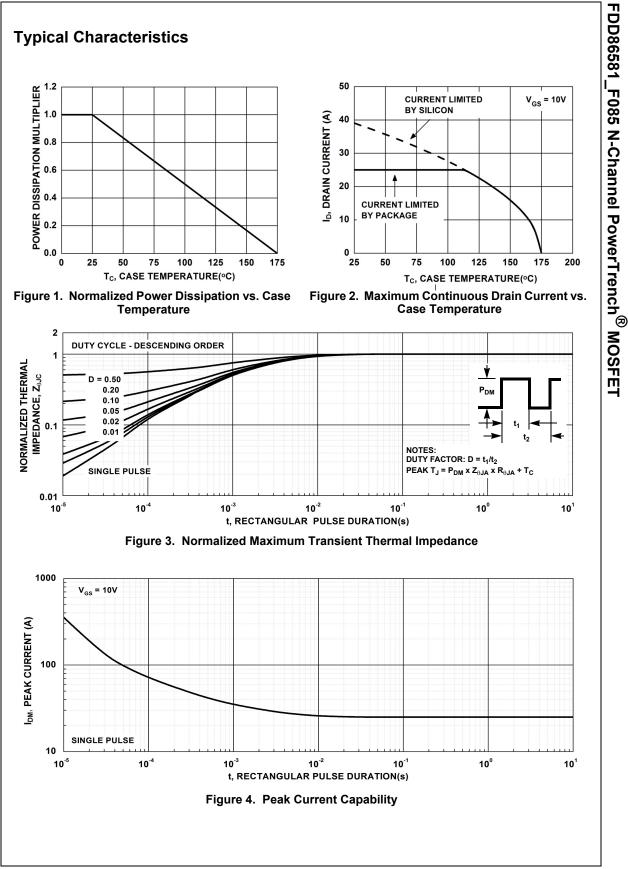
1: Current is limited by bondwire configuration.

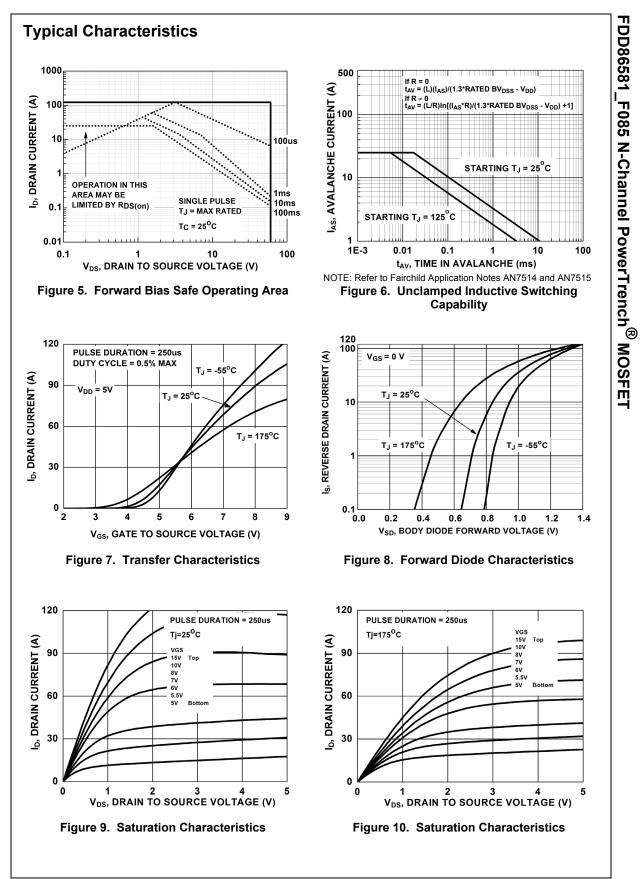
2: Starting T<sub>J</sub> = 25°C, L = 60µH, I<sub>AS</sub> = 22A, V<sub>DD</sub> = 60V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche. 3:  $R_{0JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design, while R<sub>0JA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

# Package Marking and Ordering Information

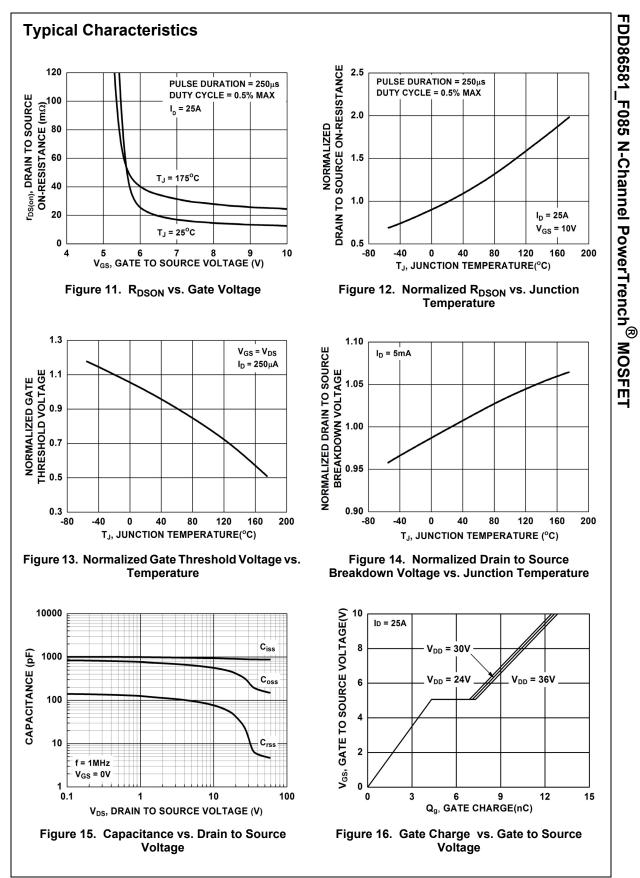
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD86581	FDD86581_F085	D-PAK(TO-252)	13"	16mm	2500units

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Units
	racteristics						
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V		60	-	-	V
		V <sub>DS</sub> =60V,		-	-	1	μA
DSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$ $T_J = 175^{\circ}C$ (Note 4)		-	-	1	mA
IGSS	Gate-to-Source Leakage Current	V <sub>GS</sub> = ±20V		-	-	±100	nA
	racteristics			-	_		
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS}$ = $V_{DS}$ , I		2.0	2.8	4.0	V
R <sub>DS(on)</sub>	Drain to Source On Resistance		$T_J = 25^{\circ}C$	-	12.3	15	mΩ
*DS(on)		$V_{GS}$ = 10V $T_{J}$ = 175°C (Note 4)		-	24.4	30	mΩ
Synami	c Characteristics			-	880	-	pF
C <sub>oss</sub>	Output Capacitance	$-V_{DS} = 30V, V_{GS} = 0V,$ -f = 1MHz $-V_{GS} = 0.5V, f = 1MHz$		-	280	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	15	-	pF
۲ <sub>q</sub>	Gate Resistance			-	3.1	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge	$V_{GS} = 0$ to 10V $V_{DD} = 30V$		-	12.6	19	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	V <sub>GS</sub> = 0 to 2	V I <sub>D</sub> = 25A	-	1.7	-	nC
ጋ <sub>gs</sub>	Gate-to-Source Gate Charge			-	4.3	-	nC
ג <sub>gd</sub>	Gate-to-Drain "Miller" Charge			-	2.8	-	nC
	ng Characteristics			_	-	21	ns
d(on)	Turn-On Delay	$V_{DD}$ = 30V, I <sub>D</sub> = 25A, V <sub>GS</sub> = 10V, R <sub>GEN</sub> = 6Ω		-	7.5	-	ns
·u(011) · ·	Rise Time			-	6.5	-	ns
d(off)	Turn-Off Delay			-	14.6	-	ns
f	Fall Time			-	4.2	-	ns
off	Turn-Off Time			-	-	28	ns
rain-S	ource Diode Characteristics						
√ <sub>SD</sub>	Source-to-Drain Diode Voltage	I <sub>SD</sub> = 25A, V <sub>GS</sub> = 0V		-	0.92	1.3	V
	-	I <sub>SD</sub> = 12.5A, V <sub>GS</sub> = 0V		-	0.85	1.2	V
t <sub>rr</sub>	Reverse-Recovery Time	$V_{DD} = 48V, I_F = 25A,$		-	35	52	ns
Q <sub>rr</sub>	Reverse-Recovery Charge	$dI_{SD}/dt = 100A/\mu s$		-	21	32	nC





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